NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE20P45Q uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =-19V,I_D =-45A

 $R_{DS(ON)} < 7m\Omega$ @ V_{GS} =-4.5V

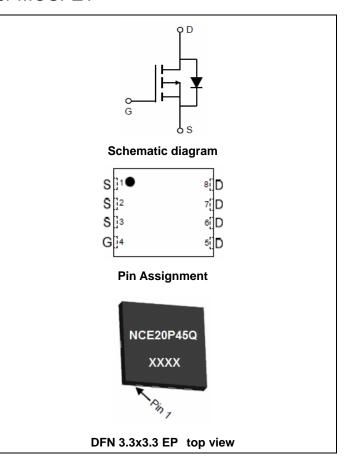
 $R_{DS(ON)} < 9m\Omega @ V_{GS} = -2.5V$

 $R_{DS(ON)}$ < 12m Ω @ V_{GS} =-1.8V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Load switch
- Battery protection



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE20P45Q	NCE20P45Q	DFN 3.3x3.3 EP	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	-19	V	
Gate-Source Voltage	V _{GS}	±12	V	
Drain Current-Continuous	I _D	-45	А	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	-35	А	
Pulsed Drain Current	I _{DM}	-200	Α	
Maximum Power Dissipation	P _D	80	W	
Derating factor		0.64	W/°C	
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	1.6	°C/W

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Electrical Characteristics (T_C=25 °C unless otherwise noted)

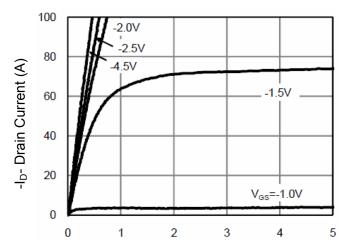
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-19	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	-0.4	-0.6	-1.0	V
		V _{GS} =-4.5V, I _D =-20A	-	5.8	7	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-2.5V, I _D =-20A	-	7.2	9	
		V _{GS} =-1.8V, I _D =-20A		9	12	
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-20A	80	-	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	C _{lss}	V _{DS} =-10V,V _{GS} =0V,	-	3500	-	PF
Output Capacitance	Coss		-	577	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	445	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	18	-	nS
Turn-on Rise Time	t _r	V_{DD} =-10V, R_{GEN} =3 Ω	-	42	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-4.5 V , R_L =0.5 Ω	-	85	-	nS
Turn-Off Fall Time	t _f		-	23	-	nS
Total Gate Charge	Qg	V _{DS} =-10V,I _D =-20A,	-	55	-	nC
Gate-Source Charge	Q _{gs}		-	10	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-4.5V	-	15	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-45	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -10A	-	47	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	53	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

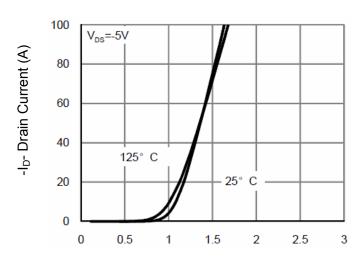
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

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Typical Electrical and Thermal Characteristics (Curves)



-Vds Drain-Source Voltage (V) **Figure 1 Output Characteristics**



-Vgs Gate-Source Voltage (V) **Figure 2 Transfer Characteristics**

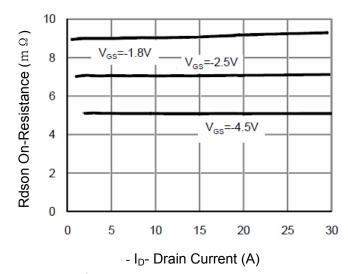


Figure 3 Rdson- Drain Current

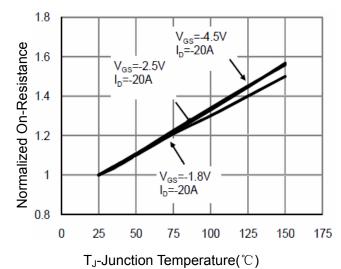


Figure 4 Rdson-Junction Temperature

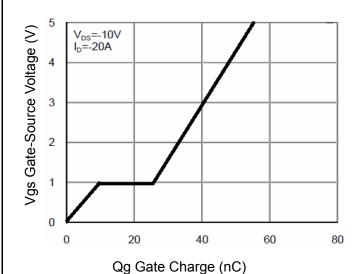


Figure 5 Gate Charge

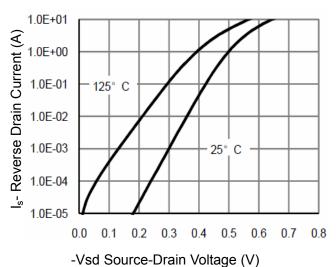


Figure 6 Source- Drain Diode Forward

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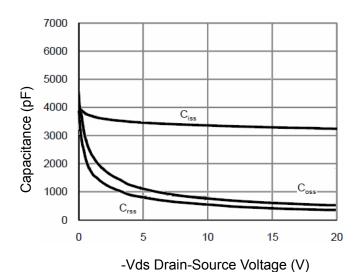


Figure 7 Capacitance vs Vds

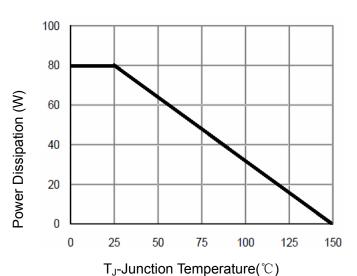


Figure 9 Power De-rating

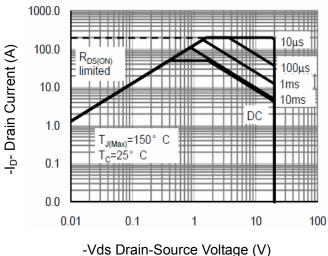
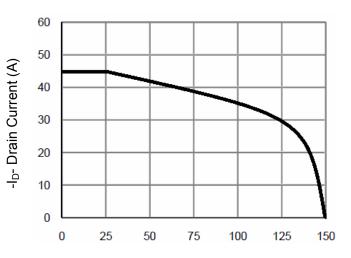


Figure 8 Safe Operation Area



T_J-Junction Temperature(°C)



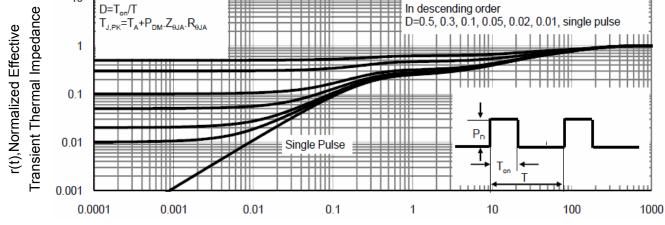
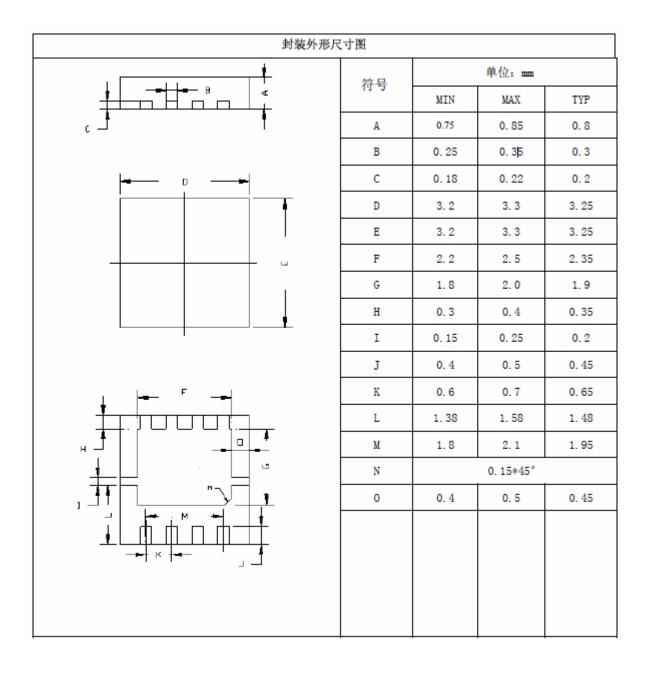


Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

DFN3.3X3.3 EP Package Information



http://www.ncepower.com

NCE20P45Q

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